

# Product data sheet

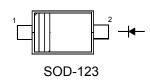
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#### Features

- Fast switching speed
- Ultra-small surface mount package
- For general purpose switching applications
- High conductance



RNNING				
PIN	DESCRIPTION			
· 1	Cathode			
2	Anode			

MARK:T4

#### Absolute Maximum Ratings (T<sub>a</sub> = 25 °C)

Parameter	Symbol	Value	Unit
Peak Reverse Voltage	V <sub>RM</sub>	100	V
Reverse Voltage	VR	75	V
Average Rectified Forward Current	I <sub>F(AV)</sub>	150	mA
Non-repetitive Peak Forward Surge Current at t = 1 µs	I <sub>FSM</sub>	2	А
Power Dissipation	P <sub>tot</sub>	400	mW
Thermal Resistance from Junction to Ambient Air	R <sub>θJA</sub>	312	°C/W
Junction Temperature	Tj	150	°C
Storage Temperature Range	T <sub>stg</sub>	- 65 to + 150	°C

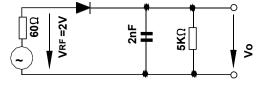
#### Characteristics at T<sub>a</sub> = 25 °C

Parameter	Symbol	Min.	Max.	Unit
Reverse Breakdown Voltage at $I_R = 1 \ \mu A$	V <sub>(BR)R</sub>	75	-	V
Forward Voltage at $I_F = 1 \text{ mA}$ at $I_F = 10 \text{ mA}$ at $I_F = 50 \text{ mA}$ at $I_F = 150 \text{ mA}$	VF	- - -	0.715 0.855 1 1.25	V
Peak Reverse Current at $V_R = 75 V$ at $V_R = 20 V$ at $V_R = 75 V$ , $T_J = 150 \circ C$ at $V_R = 25 V$ , $T_J = 150 \circ C$	I <sub>R</sub>	- - -	1 25 50 30	μA nA μA μA
Total Capacitance at V <sub>R</sub> = 0 V, f = 1 MHz	Ст	-	2	pF
Reverse Recovery Time at $I_{rr}$ = 0.1 X $I_R$ , $I_F$ = $I_R$ = 10 mA, $R_L$ = 100 $\Omega$	t <sub>rr</sub>	-	4	ns

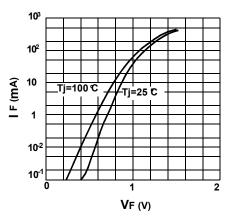


1N4148W-MS Semiconductor Compiance

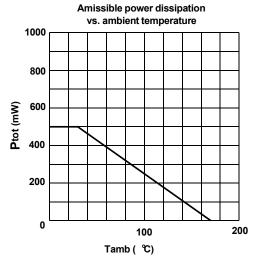
#### Forward characteristics

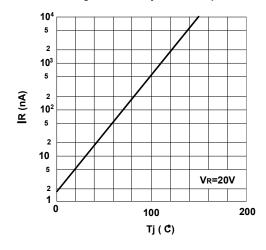


**Rectification Efficiency Measurement Circuit** 

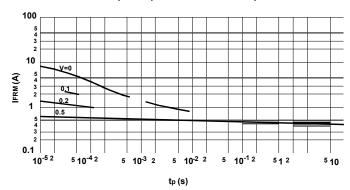


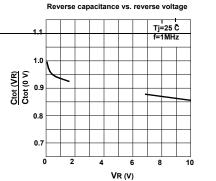
Leakage current vs. junction temperature





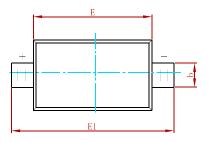


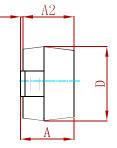




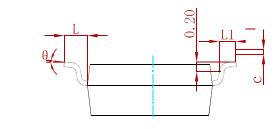


## PACKAGE MECHANICAL DATA



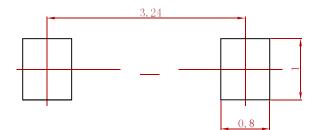


<u>A1</u>



Symbol	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.450	0.650	0.018	0.026
С	0.080	0.150	0.003	0.006
D	1.500	1.700	0.059	0.067
E	2.600	2.800	0.102	0.110
E1	3.550	3.850	0.140	0.152
L	0.500 REF		0.020	REF
L1	0.250	0.450	0.010	0.018
θ	0°	8°	0°	8°

## Suggested Pad Layout



#### Note:

1.Controlling dimension:in millimeters.

2.General tolerance:±0.05mm.

3. The pad layout is for reference purposes only.

### **REEL SPECIFICATION**

P/N	PKG	QTY
1N4148W-MS	SOD-123	3000



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